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|  | <h2>SI7980DP-T1-GE3</h2> |
| | <p>Hersteller-Teilenummer: SI7980DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V 8A PPAK SO-8</p> <p>Datenblätter:  SI7980DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 800915 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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| Teilenummer | SI7980DP-T1-GE3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET 2N-CH 20V 8A PPAK SO-8 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 800915 pcs Stock |
| Serie | TrenchFET® |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Leistung - max | 19.8W, 21.9W |
| Verpackung / Gehäuse | PowerPAK® SO-8 Dual |
| Supplier Device-Gehäuse | PowerPAK® SO-8 Dual |
| Typ FET | 2 N-Channel (Half Bridge) |
| FET-Merkmal | Standard |
| Drain-Source-Spannung (Vdss) | 20V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 8A |
| Rds On (Max) @ Id, Vgs | 22 mOhm @ 5A, 10V |
| VGS (th) (Max) @ Id | 2.5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 27nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1010pF @ 10V |
| Verpackung | Tape & Reel (TR) |










SI7980DP-T1-GE3 ist neu im Original, Suche SI7980DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7980DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7980DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

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|  <p>SI7980DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 8A PPAK SO-8</p> |  <p>SI7983DP-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 7.7A PPAK SO-8</p> |  <p>SI7983DP SI SI7983DP SI</p> |  <p>SI7972DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2 N-CH 30V POWERPAK SO8</p> |
|  <p>SI7980DP-T1-E3 Vishay / Siliconix MOSFET 2N-CH 20V 8A PPAK SO-8</p> |  <p>SI7983DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 7.7A PPAK SO-8</p> |  <p>SI7972DP-T1-GE3 Vishay / Siliconix MOSFET ARRAY 2N-CH 60V 8A SO8</p> |  <p>SI7983DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 7.7A PPAK SO-8</p> |

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|  SI7922DN-T1-GE3 |  SI7922DN-T1-GE3 |  SI7923DN-T1-E3 |  SI7923DN-T1-GE3 |  SI7923DN-T1-GE3 |
|  SI7923DN-T1-GE3 |  SI7938DP-T1-GE3 |  SI7938DP-T1-GE3 |  SI7940DP |  SI7940DP-T1-E3 |
|  SI7940DP-T1-E3 |  SI7941DP-T1-E3 |  SI7941DP-T1-GE3 |  SI7942DP |  SI7942DP-T1-E3 |
|  SI7942DP-T1-E3 |  SI7942DP-T1-GE3 |  SI7942DP-T1-GE3 |  SI7945DP-T1-E3 |  SI7945DP-T1-E3 |
|  SI7946DP |  SI7946DP-T1-E3 |  SI7946DP-T1-E3 |  SI7948DP |  SI7948DP-T1-E3 |
|  SI7949DP-T1-GE3 |  SI7949DP-T1-GE3 |  SI7956DP-T1-GE3 |  SI7956DP-T1-GE3 |  SI7958DP |
|  SI7958DP-T1-E3 |  SI7958DP-T1-E3 |  SI7958DP-T1-GE3 |  SI7958DP-T1-GE3 |  SI7960DP-T1-E3 |
|  SI7960DP-T1-E3 |  SI7960DP-T1-GE3 |  SI7960DP-T1-GE3 |  SI7964DP |  SI7964DP-T1-GE3 |
|  SI7964DP-T1-GE3 |  SI7970DP |  SI7970DP-T1-E3 |  SI7980DP-T1-E3 |  SI7980DP-T1-E3 |
|  SI7980DP-T1-GE3 |  SI7997DP-T1-GE3 |  SI7997DP-T1-GE3 |  SI7998DP-T1-GE3 |  SI7998DP-T1-GE3 |

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